Power MOSFET

40 V, 2.8 m Ω , 110 A, Single N–Channel

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- $\bullet \ Low \ Q_G$ and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit	
Drain-to-Source Voltage			V _{DSS}	40	V	
Gate-to-Source Voltage			V _{GS}	±20	V	
Continuous Drain		T _C = 25°C	I _D	110	А	
Current R _{0JC} (Notes 1, 3)	Steady	T _C = 100°C		81		
Power Dissipation $R_{\theta JC}$ (Note 1)	State	$T_{C} = 25^{\circ}C$	PD	68	W	
		$T_{C} = 100^{\circ}C$		34		
Continuous Drain Current R _{θJA} (Notes 1, 2, 3)	Steady State	T _A = 25°C	I _D	27	А	
		$T_A = 100^{\circ}C$		19	1	
Power Dissipation $R_{\theta JA}$ (Notes 1 & 2)		T _A = 25°C	PD	3.7	W	
		$T_A = 100^{\circ}C$		1.6		
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	740	А	
Operating Junction and Storage Temperature			T _J , T _{stg}	-55 to +175	°C	
Source Current (Body Diode)			ا _S	76	А	
Single Pulse Drain–to–Source Avalanche Energy (I _{L(pk)} = 7 A)			E _{AS}	215	mJ	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{ ext{ heta}JC}$	2.2	°C/W
Junction-to-Ambient - Steady State (Note 2)	Reia	41	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
Maximum current for pulses as long as 1 second is higher but is dene

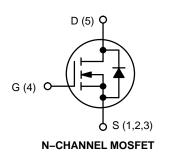
3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	2.8 mΩ @ 10 V	440.4
40 V	4.4 mΩ @ 4.5 V	110 A





ORDERING INFORMATION

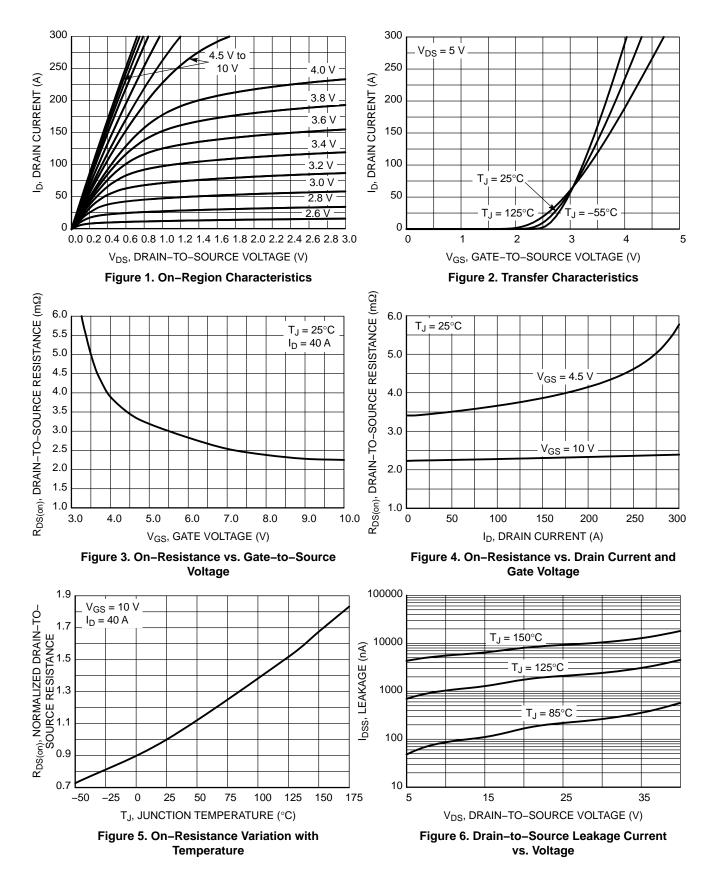
See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

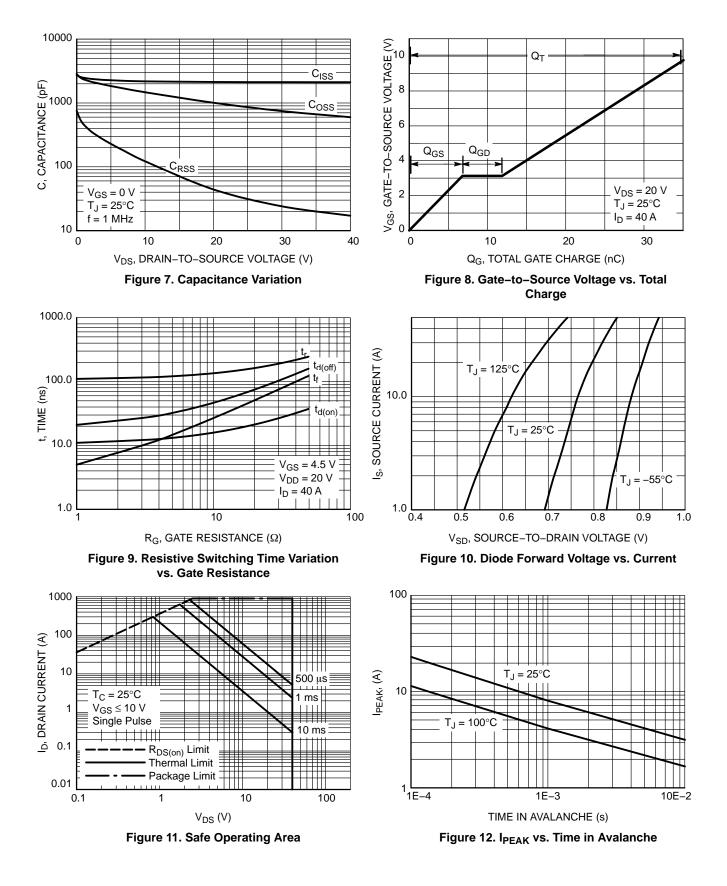
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit	
OFF CHARACTERISTICS								
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V	
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				1.6		mV/°C	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25°C			10		
		V _{DS} = 40 V	40 V T _J = 125°C		250	μΑ		
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA	
ON CHARACTERISTICS (Note 4)								
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 60 \ \mu A$		1.2		2.0	V	
Threshold Temperature Coefficient	V _{GS(TH)} /T _J	······			-5.3		mV/°C	
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 40 A		2.3	2.8	mΩ	
		V _{GS} = 4.5 V	I _D = 40 A		3.5	4.4		
Forward Transconductance	9 _{FS}	V _{DS} = 15 V, I _D = 40 A			120		S	
CHARGES, CAPACITANCES & GATE RE	SISTANCE							
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 20 V			2100			
Output Capacitance	C _{OSS}				1000		pF	
Reverse Transfer Capacitance	C _{RSS}				42			
Total Gate Charge	Q _{G(TOT)}	V_{GS} = 4.5 V, V_{DS} = 20 V; I_{D} = 40 A			16			
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 20 V; I _D = 40 A			35		1	
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS} = 20 V; I _D = 40 A			4		nC V	
Gate-to-Source Charge	Q _{GS}				7			
Gate-to-Drain Charge	Q _{GD}				5			
Plateau Voltage	V _{GP}				3.2			
SWITCHING CHARACTERISTICS (Note \$	5)							
Turn–On Delay Time	t _{d(ON)}	V_{GS} = 4.5 V, V_{DS} = 20 V, I_{D} = 40 A, R_{G} = 1.0 Ω			11			
Rise Time	tr				110		- ns	
Turn–Off Delay Time	t _{d(OFF)}				21			
Fall Time	t _f				5			
DRAIN-SOURCE DIODE CHARACTERIS	TICS							
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V,$ $I_{S} = 40 A$	T _J = 25°C		0.84	1.2		
-			T _J = 125°C		0.72		V	
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _s /dt = 100 A/µs, I _S = 40 A			41			
Charge Time	ta				19		ns	
Discharge Time	t _b				22			
Reverse Recovery Charge	Q _{RR}				30		nC	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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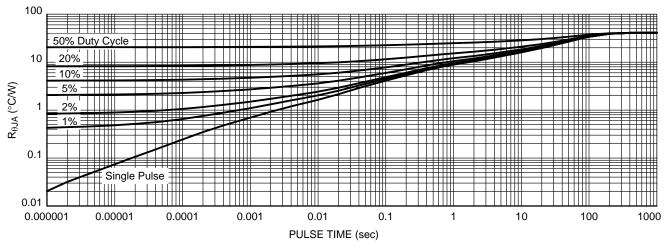


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C450NLT1G	5C450L	DFN5 (Pb–Free)	1500 / Tape & Reel
NTMFS5C450NLT3G	5C450L	DFN5 (Pb–Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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